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| Form 1449 (Rev. 2-32) U.S. Department of Commerce Patent and Trademark Office | | | | Atty. Docket No. MAN-013 | Serial No. 10/723,285 |
| Information Disclosure Statement by Applicant | | | | Applicant: Werner, et al. | |
| (Use several sheets if necessary) | | | | Filed: 11/25/03 | Group: Not Yet Avail. |

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| Examiner <i>Shaywitz</i> | Date Considered <i>1/22/04</i> |
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Examiner: Initial if citation considered, whether or not citation is in conference with MPEP 609; Draw line through citation if not conformance and not considered. Include a copy of this form with the next communication to applicant.